



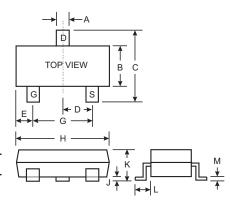
N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Features

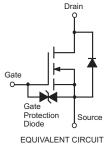
- Extremely Low On-Resistance: $170m\Omega$ @ $V_{GS} = 4.5V$
- High Drain Current: 1.1A
- Ideal for Notebook Computer, Portable Phone, PCMCIA Cards, and Battery Powered Circuits
- Lead Free By Design/RoHS Compliant (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability
- ESD Protected Gate
- "Green" Device (Note 3)

Mechanical Data

- Case: SC-59
- Case Material Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking: See Last Page
- Ordering & Date Code Information: See Last Page
- Weight: 0.008 grams (approximate)



SC-59							
Dim	Min	Max					
Α	0.30	0.50					
В	1.40	1.80					
С	2.50	3.00					
D	0.85	1.05					
E	0.30	0.70					
G	1.70	2.10					
Н	2.70	3.10					
J	_	0.10					
K	1.00	1.40					
L	0.55	0.70					
M	0.10	0.35					
All Dimensions in mm							





ESD protected

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic		Symbol	DMN100	Units	
Drain-Source Voltage		V _{DSS}	30	V	
Gate-Source Voltage	Continuous	V _{GSS}	±20	V	
Drain Current	Continuous Pulsed	I _D	1.1 4.0	А	
Total Power Dissipation		P _d	500	mW	
Thermal Resistance, Junction to Ambi	ent	$R_{ heta JA}$	250	K/W	
Operating and Storage Temperature F	Range	T _j , T _{STG}	-55 to +150	°C	

Notes:

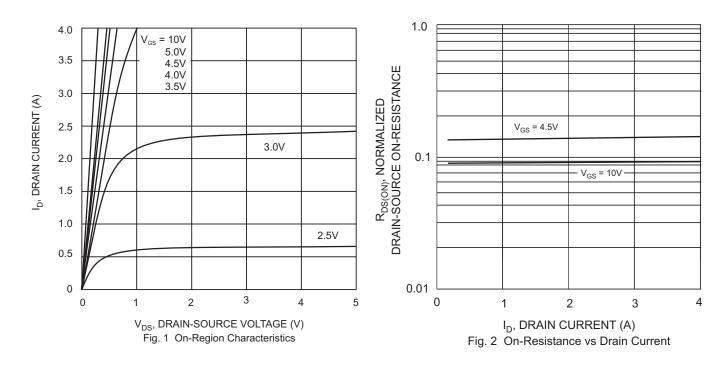
- 1. Pulse width $\leq 300 \mu s$, duty cycle $\leq 2\%$.
- 2. No purposefully added lead.
- 3. Diodes Inc.'s "Green" Policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.



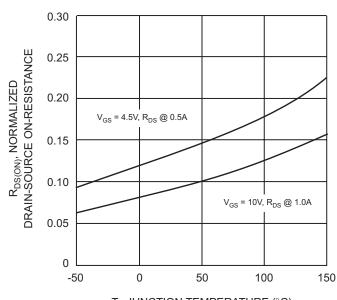
Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 1)	Symbol	IVIIII	Typ	IVICA	Oilit	rest condition		
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	V _{GS} = 0V, I _D = 250μA		
Zero Gate Voltage Drain Current $@ T_j = 25^{\circ}C$ $@ T_j = 125^{\circ}C$		_	_	1.0 10	μA	V _{DS} = 24V, V _{GS} = 0V		
Gate-Body Leakage	I _{GSS}	_	_	± 100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$		
ON CHARACTERISTICS (Note 1)	'			•		,		
Gate Threshold Voltage	V _{GS(th)}	1.0	_	3.0	V	$V_{DS} = 10V, I_{D} = 1.0mA$		
Static Drain-Source On-Resistance	R _{DS (ON)}	_	_	0.170 0.240	Ω	V _{GS} = 4.5V, I _D = 0.5A V _{GS} = 10V, I _D = 1.0A		
Forward Transconductance	g FS	1.3	2.4	_	S	V _{DS} = 10V, I _D =0.5A		
DYNAMIC CHARACTERISTICS								
Input Capacitance		_	150	_	pF			
Output Capacitance	Coss	_	90	_	pF	$V_{DS} = 10V, V_{GS} = 0V$ f = 1.0MHz		
Reverse Transfer Capacitance	C _{rss}	_	30	_	pF			
Total Gate Charge	Qg	_	5.5	_	nC	V 04V L 4.04		
Gate-to-Source Charge	Q _{gs}	_	0.8	_	nC	$V_{DS} = 24V, I_D = 1.0A,$ $V_{GS} = 10V$		
Gate-to-Drain Charge	Q _{gd}	_	1.3	_	nC	- 40		
SWITCHING CHARACTERISTICS								
Turn-On Delay Time	t _{D(ON)}	_	10	_	ns			
Turn-Off Delay Time	t _{D(OFF)}	_	25	_	ns	$V_{DD} = 10V, I_D = 0.5A,$		
Turn-On Rise Time	t _r	_	15	_	ns	$V_{GS} = 5.0V$, $R_{GEN} = 50\Omega$		
Turn-Off Fall Time	t _f	_	45	_	ns			
SOURCE- DRAIN RATINGS (BODY DIODE)								
Continuous Source Current				0.54	Α	_		
Pulse Source Current	I _{SM}	_	_	4.0	Α	_		
Forward Voltage	V _{SD}	_	_	1.2	V	I _F = 1.0A, V _{GS} = 0V		
Reverse Recovery Time	t _{rr}	_	35	_	ns	I _F = 1.0A, di/dt = 50A/μs		

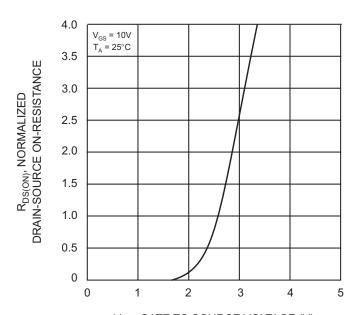
Notes: 1. Pulse width $\leq 300 \mu s$, duty cycle $\leq 2\%$.







 $\rm T_{j}, \, JUNCTION \, TEMPERATURE \, (^{\circ}C)$ Fig. 3 On-Resistance vs Junction Temperature



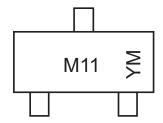
V_{GS}, GATE TO SOURCE VOLTAGE (V) Fig. 4 On-Resistance vs Gate-Source Voltage

Ordering Information (Note 4)

Device	Packaging	Shipping
DMN100-7-F	SC-59	3000/Tape & Reel

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



M11 = Product Type Marking Code YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	2006	2007	2008	2009
Code	Т	U	V	W

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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